#### TOSHIBA Photocoupler Photorelay

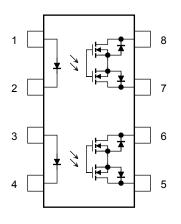
# TLP202A

Telecommunications
Measurement and Control Equipment
Data Acquisition System
Measurement Equipment

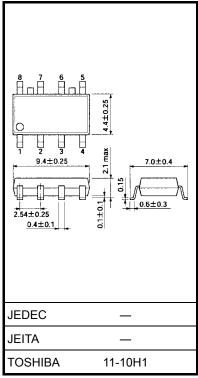
The Toshiba TLP202A consists of a gallium arsenide infrared emitting diode optically coupled to a photo-MOSFET in an 8-pin SOP package. This photorelay has higher output current rating than phototransistor-type photocoupler; hence, it is suitable for use as On/Off control for high current.

- 8-pin SOP (2.54SOP8): Height = 2.1 mm, pitch = 2.54 mm
- Normally open (1-form-A) device
- Peak off-state voltage: 60 V (min)
- Trigger LED current: 3 mA (max)
- On-state current: 400 mA (max)
- On-state resistance:  $2 \Omega$  (max)
- Isolation voltage: 1500 Vrms (min)
- UL recognized: UL1557, File No.E67349

#### Pin Configuration (top view)



1, 3 : Anode 2, 4 : Cathode 5 : Drain D1 6 : Drain D2 7 : Drain D3 8 : Drain D4 Unit: mm



Weight: 0.2 g (typ.)

#### Absolute Maximum Rating (Ta = 25°C)

Characteristics		Symbol	Rating	Unit
LED	Forward current	lF	50	mA
	Forward current derating (Ta ≥ 25°C)	∆l <sub>F</sub> /°C	-0.5	mA/°C
	Peak forward current (100 μs pulse, 100 pps)	I <sub>FP</sub>	1	Α
	Reverse voltage	$V_{R}$	5	V
	Junction temperature	Tj	125	°C
	Off-state output terminal voltage	V <sub>OFF</sub>	60	V
Detector	On-state current	I <sub>ON</sub>	400	mA
Detector	Forward current derating (Ta ≥ 25°C)	Δl <sub>ON</sub> /°C	-4.0	mA/°C
	Junction temperature	Tj	125	°C
Storage to	Storage temperature		-55 to 125	°C
Operating temperature		T <sub>opr</sub>	-40 to 85	°C
Lead soldering temperature (10 s)		T <sub>sol</sub>	260	°C
Isolation voltage (AC, 1 min, R.H. $\leq$ 60%) (Note 1)		BVS	1500	Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: LED pins are shorted together. Detector pins are also shorted together.

#### **Recommended Operating Conditions**

Characteristics	Symbol	Min	Тур.	Max	Unit
Supply voltage	$V_{DD}$	_	_	48	V
Forward current	lF	5	7.5	25	mA
On-state current	I <sub>ON</sub>	_	_	400	mA
Operating temperature	T <sub>opr</sub>	-20		65	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

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# **Electrical Characteristics (Ta = 25°C)**

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
LED	Forward voltage	V <sub>F</sub>	I <sub>F</sub> = 10 mA	1.0	1.15	1.3	V
	Reverse current	I <sub>R</sub>	V <sub>R</sub> = 5 V	_	_	10	μΑ
	Capacitance	C <sub>T</sub>	V = 0, f = 1 MHz	_	30	_	pF
Detector	Off-state current	loff	V <sub>OFF</sub> = 60 V	_	_	1	μΑ
	Capacitance	C <sub>OFF</sub>	V = 0, f = 1 MHz	_	130		pF

# **Coupled Electrical Characteristics (Ta = 25°C)**

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Trigger LED current	I <sub>FT</sub>	I <sub>ON</sub> = 400 mA	_	1.6	3	mA
Return LED current	I <sub>FC</sub>	I <sub>OFF</sub> = 100 μA	0.1	_	_	mA
On-state resistance	R <sub>ON</sub>	I <sub>ON</sub> = 400 mA, I <sub>F</sub> = 5 mA	_	1	2	Ω

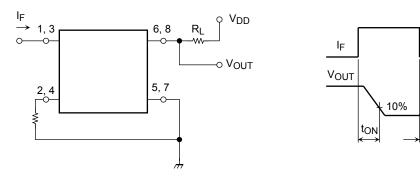
# Isolation Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Capacitance input to output	CS	V <sub>S</sub> = 0 V, f = 1 MHz	_	8.0	_	pF
Isolation resistance	R <sub>S</sub>	V <sub>S</sub> = 500 V, R.H. ≦ 60%	$5 \times 10^{10}$	10 <sup>14</sup>	_	Ω
	BVS	AC, 1 min	1500	_	_	Vrms
Isolation voltage		AC, 1 s, in oil	_	3000	_	VIIIIS
		DC, 1 min, in oil	_	3000	_	Vdc

# **Switching Characteristics (Ta = 25°C)**

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Turn-on time	t <sub>ON</sub>	$R_L = 200 \Omega$ (Note 2)	_	8.0	2	ms
Turn-off time	toff	V <sub>DD</sub> = 20 V, I <sub>F</sub> = 5 mA	_	0.1	0.5	1115

Note 2: Switching time test circuit



90%

toff

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